

$$I_{F(AV)} = 4.7 \text{ A}$$
$$V_{RRM} = 32000 \text{ V}$$

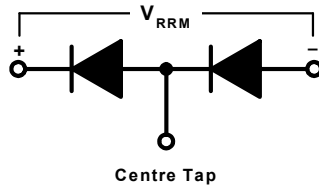
High Voltage Diode Rectifier Module

LARONTROL

Electronic Devices

Type Number	Repetitive Peak	Minimum Avalanche Voltage $V_{(BR)R}$
HTZ280H32K	32000	34000
HTZ280H28K	28000	30000
HTZ280H24K	24000	26000
HTZ280H20K	20000	22000

CIRCUIT DIAGRAM



CURRENT RATINGS - AIR COOLED

$I_{F(AV)}$	Mean forward current	Half wave resistive load $T_{amb} = 35^{\circ}C$	4.7	A
I_F	Continuous (direct) forward current	$T_{amb} = 35^{\circ}C$	5.7	A
$R_{th(j-a)}$	Thermal resistance junction to ambient		0.95	$^{\circ}C/W$

CURRENT RATINGS - OIL COOLED

$I_{F(AV)}$	Mean forward current	Half wave resistive load $T_{oil} = 60^{\circ}C$	4.5	A
I_T	Continuous (direct) forward current	$T_{oil} = 60^{\circ}C$	5.5	A
$R_{th(j-o)}$	Thermal resistance junction to oil		0.77	$^{\circ}C/W$

SURGE RATINGS

I²t	I ² t for fusing	10 ms half sine T _{vj} = 150°C	200 A ² sec
I_{FSM}	Surge (non-repetitive) forward current	T _{vj} = 150°C	200 A

TEMPERATURE AND FREQUENCY RATINGS

T_{vj}	Virtual junction temperature	Forward (conducting)	180	°C
		Reverse (blocking)	180	°C
T_{stg}	Storage temperature range		-40 to 100	°C
f	Frequency range		20 to 400	Hz

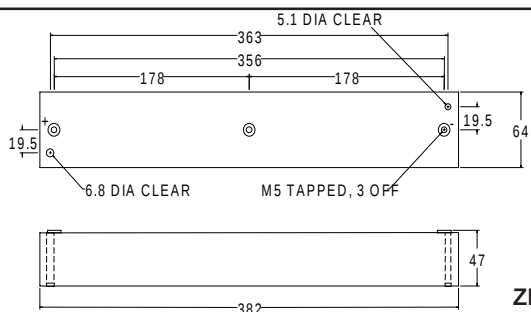
CHARACTERISTICS $T_{\text{case}} = 25^{\circ}\text{C}$ unless otherwise stated

V_{FM}	Forward voltage	At 12 Amps peak	max 23	V
I_{RM}	Peak reverse current	At V_{RRM} ; $T_{case} = 150^{\circ}C$	max 0.5	mA

Dimensioned Outlines

Dimensions shown are maximum in mm

Weight typ.: 2,0 Kg



IXYS reserves the right to change limits, test conditions and dimensions.

ZH

Issue 1 June 1998

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HTZ280H Series

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$$V_{RRM} = 32000 \text{ V}$$

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